# MCP111/112

# **Micropower Voltage Detector**

#### **Features**

- MCP111: Passes AEC-Q100 Reliability Testing
- Ultra-Low Supply Current: 1.75 μA (Max.)
- · Precision Monitoring Options Of:
  - 1.90V, 2.32V, 2.63V, 2.90V, 2.93V, 3.08V, 4.38V and 4.63V
- · Resets Microcontroller in a Power-Loss Event
- Active-Low V<sub>OUT</sub> Pin:
  - MCP111 Active-Low, Open-Drain
  - MCP112 Active-Low, Push-Pull
- Available in SOT23-3, TO-92, SC-70 and SOT-89-3 Packages
- · Temperature Range:
  - Extended: -40°C to +125°C (except MCP1XX-195)
  - Industrial: -40°C to +85°C (MCP1XX-195 Only)
- · Pb-Free Devices

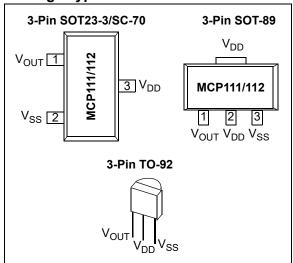
## **Applications**

- Critical Microcontroller and Microprocessor Power-Monitoring Applications
- Computers
- · Intelligent Instruments
- · Portable Battery-Powered Equipment

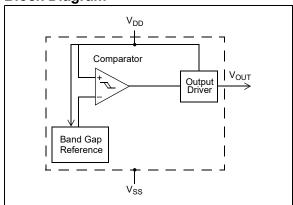
#### **General Description**

The MCP111/112 are voltage-detecting devices designed to keep a microcontroller in reset until the system voltage has stabilized at the appropriate level for reliable system operation. These devices also operate as protection from brown-out conditions when the system supply voltage drops below the specified threshold voltage level. Eight different trip voltages are available.

#### **Package Types**



## **Block Diagram**



## **DEVICE FEATURES**

D i	Output		Reset Delay	SOT-23/SC70	
Device	Туре	Pull-up Resistor	(typ.)	Package Pin Out (Pin # 1, 2, 3)	Comment
MCP111	Open-drain	External	No	$V_{OUT}, V_{SS}, V_{DD}$	
MCP112	Push-pull	No	No	$V_{OUT}, V_{SS}, V_{DD}$	
MCP102	Push-pull	No	120 ms	$\overline{\text{RST}}$ , $V_{\text{DD}}$ , $V_{\text{SS}}$	See MCP102/103/121/131 Data Sheet (DS20001906)
MCP103	Push-pull	No	120 ms	Vss, RST, V <sub>DD</sub>	See MCP102/103/121/131 Data Sheet (DS20001906)
MCP121	Open-drain	External	120 ms	RST, V <sub>DD</sub> , V <sub>SS</sub>	See MCP102/103/121/131 Data Sheet (DS20001906)
MCP131	Open-Drain	Internal (~95 kΩ)	120 ms	RST, V <sub>DD</sub> , V <sub>SS</sub>	See MCP102/103/121/131 Data Sheet (DS20001906)

## 1.0 ELECTRICAL CHARACTERISTICS

## Absolute Maximum Ratings<sup>†</sup>

V <sub>DD</sub>	7.0V
Input current (V <sub>DD</sub> )	10 mA
Output current (RST)	10 mA
Rated Rise Time of V <sub>DD</sub>	100V/µs
All inputs and outputs (except RST) w.r.t. V <sub>SS</sub>	–0.6V to (V <sub>DD</sub> + 1.0V)
RST output w.r.t. V <sub>SS</sub>	0.6V to 13.5V
Storage temperature	65°C to + 150°C
Ambient temp. with power applied	40°C to + 125°C
Maximum Junction temp. with power applied	150°C
ESD protection on all pins	
НВМ	2 kV
MM	
CDM	1.5 kV (MCP111 only)

**Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

## **DC CHARACTERISTICS**

**Electrical Specifications:** Unless otherwise indicated, all limits are specified for  $V_{DD}$  = 1V to 5.5V,  $R_{PU}$  = 100 k $\Omega$  (only **MCP111**),  $T_{\Delta}$  = -40°C to +125°C.

Paran	neters	Symbol	Min.	Тур.	Max.	Units	Conditions
				ıyp.			Containons
Operating Voltage Range		$V_{DD}$	1.0		5.5	V	
Specified V <sub>DD</sub> Value to	V <sub>OUT</sub> low	$V_{DD}$	1.0	_		V	$I_{\overline{RST}} = 10 \mu A, V_{\overline{RST}} < 0.2V$
Operating Current		$I_{DD}$		< 1	1.75	μΑ	
	MCP1XX-195		1.872	1.900	1.929	V	T <sub>A</sub> = +25°C (Note 1)
			1.853	1.900	1.948	V	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C (Note 2)}$
	MCP1XX-240		2.285	2.320	2.355	V	T <sub>A</sub> = +25°C (Note 1)
			2.262	2.320	2.378	V	Note 2
	MCP1XX-270		2.591	2.630	2.670	V	T <sub>A</sub> = +25°C (Note 1)
			2.564	2.630	2.696	V	Note 2
V Trip Doint	MCP1XX-290		2.857	2.900	2.944	V	T <sub>A</sub> = +25°C (Note 1)
V <sub>DD</sub> Trip Point		V <sub>TRIP</sub>	2.828	2.900	2.973	V	Note 2
	MCP1XX-300		2.886	2.930	2.974	V	T <sub>A</sub> = +25°C (Note 1)
			2.857	2.930	3.003	V	Note 2
	MCP1XX-315		3.034	3.080	3.126	V	T <sub>A</sub> = +25°C (Note 1)
			3.003	3.080	3.157	V	Note 2
	MCP1XX-450		4.314	4.380	4.446	V	T <sub>A</sub> = +25°C (Note 1)
			4.271	4.380	4.490	V	Note 2

- Note 1: Trip point is  $\pm 1.5\%$  from typical value.
  - 2: Trip point is ±2.5% from typical value.
  - 3: This specification allows this device to be used in PIC<sup>®</sup> microcontroller applications that require the In-Circuit Serial Programming™ (ICSP™) feature (see device-specific programming specifications for voltage requirements). This specification DOES NOT allow a continuous high voltage to be present on the open-drain output pin (V<sub>OUT</sub>). The total time that the V<sub>OUT</sub> pin can be above the maximum device operational voltage (5.5V) is 100 sec. Current into the V<sub>OUT</sub> pin should be limited to 2 mA. It is recommended that the device operational temperature be maintained between 0°C to 70°C (+25°C preferred). For additional information, please refer to Figure 2-28.
  - 4: This parameter is established by characterization and is not 100% tested.

## DC CHARACTERISTICS (CONTINUED)

**Electrical Specifications:** Unless otherwise indicated, all limits are specified for  $V_{DD}$  = 1V to 5.5V,  $R_{PU}$  = 100 k $\Omega$  (only **MCP111**),  $T_A = -40$ °C to +125°C.

Parameters		Symbol	Min.	Тур.	Max.	Units	Conditions
V Trin Daint	MCP1XX-475	.,	4.561	4.630	4.700	V	T <sub>A</sub> = +25°C (Note 1)
V <sub>DD</sub> Trip Point	WICP1XX-4/5	V <sub>TRIP</sub>	4.514	4.630	4.746	V	Note 2
V <sub>DD</sub> Trip Point Tempco		T <sub>TPCO</sub>	_	±100	_	ppm/°	
	MCP1XX-195		0.019	_	0.114	V	T <sub>A</sub> = +25°C
	MCP1XX-240		0.023	_	0.139	V	
	MCP1XX-270		0.026	_	0.158	V	
Threshold Hysteresis	MCP1XX-290	\ \ <u>\</u>	0.029	_	0.174	V	
(min. = 1%, max = 6%)	MCP1XX-300	V <sub>HYS</sub>	0.029	_	0.176	V	
	MCP1XX-315		0.031	_	0.185	V	
	MCP1XX-450		0.044	_	0.263	V	
	MCP1XX-475		0.046	_	0.278	V	
V <sub>OUT</sub> Low-level Output Vol	tage	V <sub>OL</sub>	1	_	0.4	V	$I_{OL} = 500 \mu A, V_{DD} = V_{TRIP(MIN)}$
V <sub>OUT</sub> High-level Output Vo	Itage	V <sub>OH</sub>	V <sub>DD</sub> – 0.6	_	_	V	I <sub>OH</sub> = 1 mA, For only <b>MCP112</b> (push-pull output)
Open-drain High Voltage on Output		V <sub>ODH</sub>	-	_	13.5 <sup>(3)</sup>	V	MCP111 only, V <sub>DD</sub> = 3.0V, Time voltage > 5.5V applied ≤ 100s, current into pin limited to 2 mA, +25°C operation recommended Note 3, Note 4
Open-drain Output Leakag ( <b>MCP111</b> only)	e Current	I <sub>OD</sub>	_	0.1	_	μΑ	

- Note 1: Trip point is  $\pm 1.5\%$  from typical value.
  - 2: Trip point is ±2.5% from typical value.
  - 3: This specification allows this device to be used in PIC<sup>®</sup> microcontroller applications that require the In-Circuit Serial Programming (ICSP<sup>™</sup>) feature (see device-specific programming specifications for voltage requirements). This specification DOES NOT allow a continuous high voltage to be present on the open-drain output pin (V<sub>OUT</sub>). The total time that the V<sub>OUT</sub> pin can be above the maximum device operational voltage (5.5V) is 100 sec. Current into the V<sub>OUT</sub> pin should be limited to 2 mA. It is recommended that the device operational temperature be maintained between 0°C to 70°C (+25°C preferred). For additional information, please refer to Figure 2-28.
  - 4: This parameter is established by characterization and is not 100% tested.

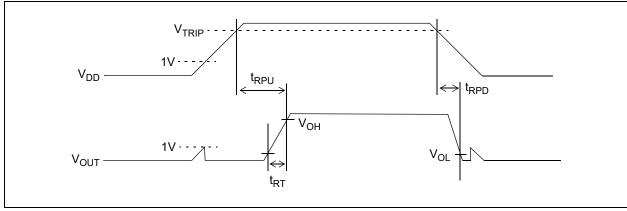


FIGURE 1-1: Timing Diagram.

## **AC CHARACTERISTICS**

**Electrical Specifications:** Unless otherwise indicated, all limits are specified for  $V_{DD}$  = 1V to 5.5V,  $R_{PU}$  = 100 k $\Omega$  (only **MCP111**),  $T_A$  = -40°C to +125°C.

Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions
V <sub>DD</sub> Detect to V <sub>OUT</sub> Inactive	t <sub>RPU</sub>	_	90	_	μs	Figure 1-1 and C <sub>L</sub> = 50 pF (Note 1)
V <sub>DD</sub> Detect to V <sub>OUT</sub> Active	t <sub>RPD</sub>	_	130	_	μs	V <sub>DD</sub> ramped from V <sub>TRIP(MAX)</sub> + 250 mV down to V <sub>TRIP(MIN)</sub> - 250 mV, per <b>Figure 1-1</b> , C <sub>L</sub> = 50 pF ( <b>Note 1</b> )
V <sub>OUT</sub> Rise Time After V <sub>OUT</sub> Active	t <sub>RT</sub>		5		μs	For V <sub>OUT</sub> 10% to 90% of final value per <b>Figure 1-1</b> , C <sub>L</sub> = 50 pF (Note 1)

Note 1: These parameters are for design guidance only and are not 100% tested.

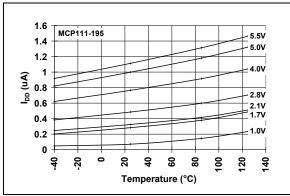
## **TEMPERATURE CHARACTERISTICS**

**Electrical Specifications:** Unless otherwise noted, all limits are specified for  $V_{DD}$  = 1V to 5.5V,  $R_{PU}$  = 100 kΩ (MCP111 only),  $T_A$  = -40°C to +125°C.

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Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions			
Temperature Ranges									
Specified Temperature Range	T <sub>A</sub>	-40	_	+85	°C	MCP1XX-195			
Specified Temperature Range	T <sub>A</sub>	-40	_	+125	°C	Except MCP1XX-195			
Maximum Junction Temperature	TJ	_	_	+150	°C				
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C				
Package Thermal Resistances									
Thermal Resistance, 3L-SOT23	$\theta_{JA}$	_	336	_	°C/W				
Thermal Resistance, 3L-SC-70	$\theta_{JA}$	_	340	_	°C/W				
Thermal Resistance, 3L-TO-92	$\theta_{JA}$	_	131.9	_	°C/W				
Thermal Resistance, 3L-SOT-89	$\theta_{\sf JA}$	_	110	_	°C/W				

## 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



**FIGURE 2-1:**  $I_{DD}$  vs. Temperature (MCP111-195).

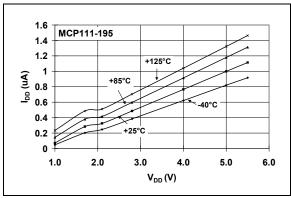
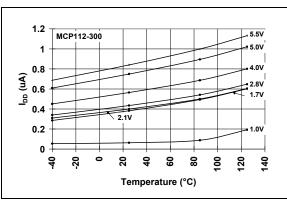
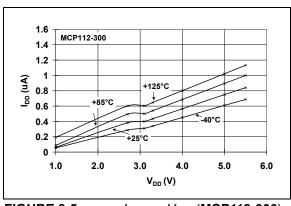


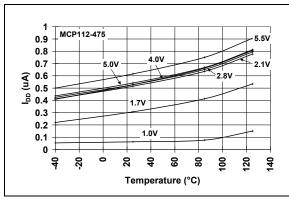
FIGURE 2-4: I<sub>DD</sub> vs. V<sub>DD</sub> (MCP111-195).



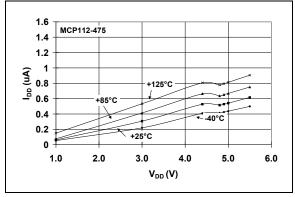
**FIGURE 2-2:** I<sub>DD</sub> vs. Temperature (MCP112-300).



**FIGURE 2-5:**  $I_{DD}$  vs.  $V_{DD}$  (MCP112-300).

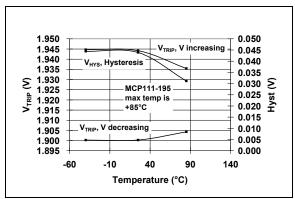


**FIGURE 2-3:**  $I_{DD}$  vs. Temperature (MCP112-475).

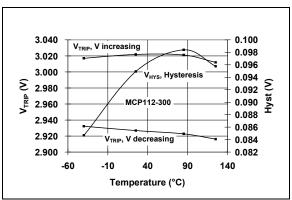


**FIGURE 2-6:**  $I_{DD}$  vs.  $V_{DD}$  (**MCP112-475**).

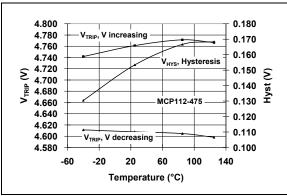
# MCP111/112



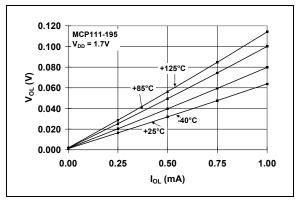
**FIGURE 2-7:**  $V_{TRIP}$  and  $V_{HYST}$  vs. Temperature (**MCP111-195**).



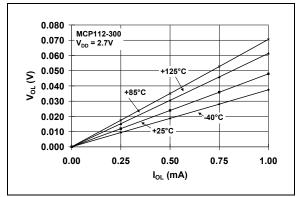
**FIGURE 2-8:**  $V_{TRIP}$  and  $V_{HYST}$  vs. Temperature (**MCP112-300**).



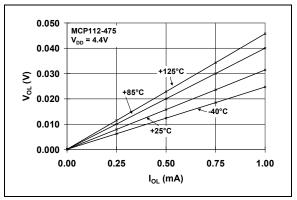
**FIGURE 2-9:**  $V_{TRIP}$  and  $V_{HYST}$  vs. Temperature (**MCP112-475**).



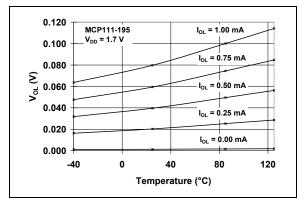
**FIGURE 2-10:**  $V_{OL}$  vs.  $I_{OL}$  (MCP111-195 @  $V_{DD}$  = 1.7V).



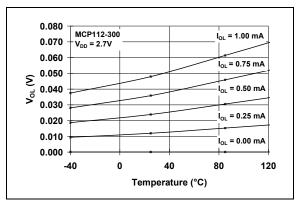
**FIGURE 2-11:**  $V_{OL}$  vs.  $I_{OL}$  (MCP112-300 @  $V_{DD}$  = 2.7V).



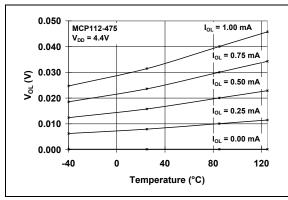
**FIGURE 2-12:**  $V_{OL}$  vs.  $I_{OL}$  (MCP112-475 @  $V_{DD}$  = 4.4V).



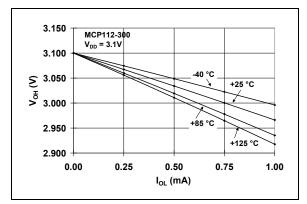
**FIGURE 2-13:**  $V_{OL}$  vs. Temperature (MCP111-195 @  $V_{DD}$  = 1.7V).



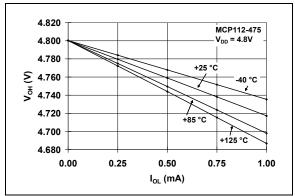
**FIGURE 2-14:**  $V_{OL}$  vs. Temperature (MCP112-300 @  $V_{DD}$  = 2.7V).



**FIGURE 2-15:**  $V_{OL}$  vs. Temperature (MCP112-475 @  $V_{DD} = 4.4V$ ).



**FIGURE 2-16:**  $V_{OH}$  vs.  $I_{OH}$  (MCP112-300 @  $V_{DD}$  = 3.1V).



**FIGURE 2-17:**  $V_{OH}$  vs.  $I_{OH}$  (MCP112-475 @  $V_{DD}$  = 4.8V).

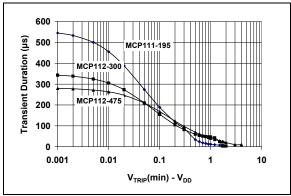
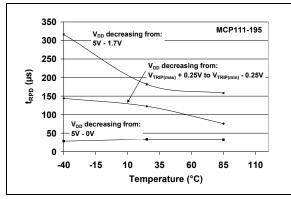
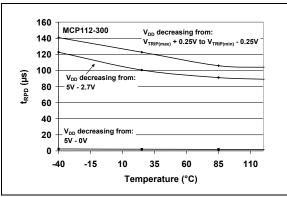


FIGURE 2-18: Typical Transient Response (25 °C).

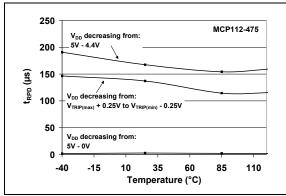
# MCP111/112



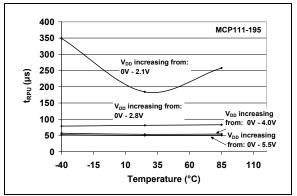
**FIGURE 2-19:**  $t_{RPD}$  vs. Temperature (MCP111-195).



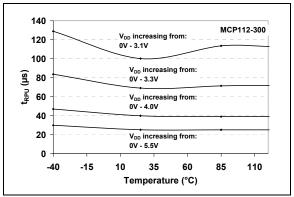
**FIGURE 2-20:**  $t_{RPD}$  vs. Temperature (MCP112-300).



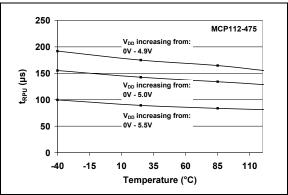
**FIGURE 2-21:**  $t_{RPD}$  vs. Temperature (MCP112-475).



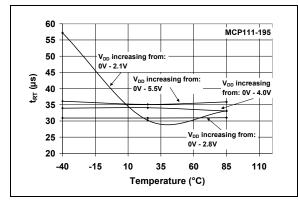
**FIGURE 2-22:**  $t_{RPU}$  vs. Temperature (MCP111-195).



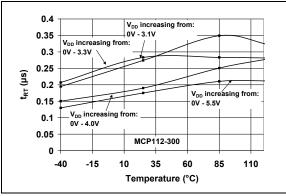
**FIGURE 2-23:**  $t_{RPU}$  vs. Temperature (MCP112-300).



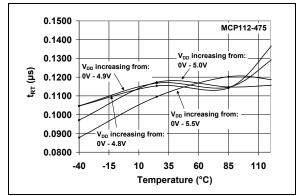
**FIGURE 2-24:**  $t_{RPU}$  vs. Temperature (MCP112-475).



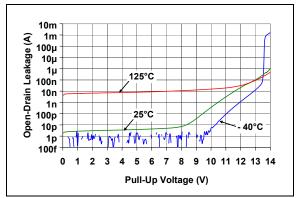
**FIGURE 2-25:**  $t_{RT}$  vs. Temperature (MCP111-195).



**FIGURE 2-26:**  $t_{RT}$  vs. Temperature (MCP112-300).



**FIGURE 2-27:**  $t_{RT}$  vs. Temperature (MCP112-475).



**FIGURE 2-28:** Open-Drain Leakage Current vs. Voltage Applied to  $V_{OUT}$  Pin (MCP111-195).

# MCP111/112

## 3.0 PIN DESCRIPTION

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

P	in Number						
SOT-23-3 SC-70	SOT-89-3	T0-92	Symbol	Function			
1	1	1	V <sub>OUT</sub>	Output State			
				V <sub>DD</sub> Falling:			
				$H = V_{DD} > V_{TRIP}$			
				$L = V_{DD} < V_{TRIP}$			
				.,			
				V <sub>DD</sub> Rising:			
				$H = V_{DD} > V_{TRIP} + V_{HYS}$			
				$L = V_{DD} < V_{TRIP} + V_{HYS}$			
2	3	3	$V_{SS}$	Ground reference			
3	2	2	$V_{DD}$	Positive power supply			
_	4	_	$V_{DD}$	Positive power supply			

## 4.0 APPLICATION INFORMATION

For many of today's microcontroller applications, care must be taken to prevent low-power conditions that can cause many different system problems. The most common causes is a brown-out condition, where the system supply drops below the operating level momentarily. The second most common cause is when a slowly decaying power supply causes the microcontroller to begin executing instructions without sufficient voltage to sustain SRAM, thus producing indeterminate results. Figure 4-1 shows a typical application circuit.

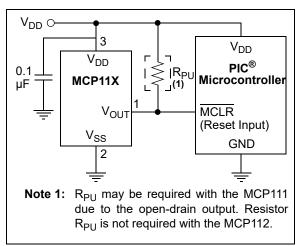
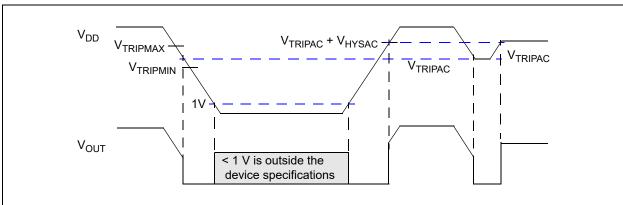


FIGURE 4-1: Typical Application Circuit.

## 4.1 V<sub>TRIP</sub> Operation

The voltage trip point (V<sub>TRIP</sub>) is determined on the falling edge of V<sub>DD</sub>. The actual voltage trip point (V<sub>TRIPAC</sub>) will be between the minimum trip point (V<sub>TRIPMIN</sub>) and the maximum trip point (V<sub>TRIPMAX</sub>). There is a hysteresis on this trip point to remove any "jitter" that would occur on the V<sub>OUT</sub> pin when the device V<sub>DD</sub> is at the trip point.

Figure 4-2 shows the state of the  $V_{OUT}$  pin as determined by the  $V_{DD}$  voltage. The  $V_{TRIP}$  specification is for falling  $V_{DD}$  voltages. When the  $V_{DD}$  voltage is rising, the  $V_{OUT}$  pin will not be driven high until  $V_{DD}$  is at  $V_{TRIP} + V_{HYS}$ .



**FIGURE 4-2:**  $V_{OUT}$  Operation as Determined by the  $V_{TRIP}$  and  $V_{HYS}$ .

## 4.2 Negative Going V<sub>DD</sub> Transients

The minimum pulse width (time) required to cause a reset may be an important criteria in the implementation of a Power-on Reset (POR) circuit. This time is referred to as transient duration, defined as the amount of time needed for these supervisory devices to respond to a drop in  $V_{DD}.$  The transient duration time is dependent on the magnitude of  $V_{TRIP} - V_{DD}.$  Generally speaking, the transient duration decreases with increases in  $V_{TRIP} - V_{DD}.$ 

Figure 4-3 shows a typical transient duration vs. reset comparator overdrive for which the MCP111/112 will not generate a reset pulse. It shows that the farther below the trip point the transient pulse goes, the duration of the pulse required to cause a reset gets shorter. Figure 2-18 shows the transient response characteristics for the MCP111/112.

A 0.1  $\mu F$  bypass capacitor, mounted as close as possible to the  $V_{DD}$  pin, provides additional transient immunity (refer to Figure 4-1).

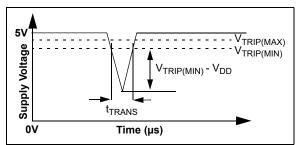


FIGURE 4-3: Example of Typical Transient Duration Waveform.

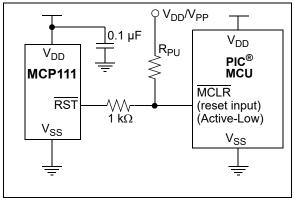
# 4.3 Effect of Temperature on Time-Out Period (t<sub>RPU</sub>)

The time-out period ( $t_{RPU}$ ) determines how long the device remains in the reset condition. This is affected by both  $V_{DD}$  and temperature. The graph shown in Figures 2-22, 2-23 and 2-24 show the typical response for different  $V_{DD}$  values and temperatures.

# 4.4 Using in PIC<sup>®</sup> Microcontroller ICSP™ Applications (MCP111 only)

Figure 4-4 shows the typical application circuit for using the MCP111 for voltage supervisory function when the PIC microcontroller will be programmed via the In-Circuit Serial Programming™ (ICSP) feature. Additional information is available in TB087, "Using Voltage Supervisors with PIC® Microcontroller Systems which Implement In-Circuit Serial Programming™", DS91087.

Note: It is recommended that the current into the RST pin be current limited by a 1 k $\Omega$  resistor.

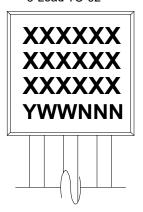


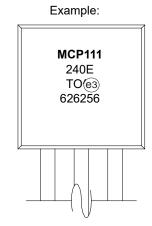
**FIGURE 4-4:** Typical Application Circuit for  $PIC^{\textcircled{\tiny{\$}}}$  Microcontroller with the ICSP<sup>TM</sup> feature.

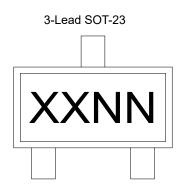
## 5.0 PACKAGING INFORMATION

## 5.1 Package Marking Information

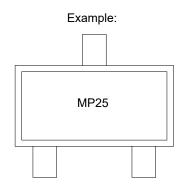
3-Lead TO-92







Device	Code
MCP111T-195I/TT	MP
MCP111T-240ETT	MQ
MCP111T-270E/TT	MG
MCP111T-290E/TT	NH
MCP111T-300E/TT	MJ
MCP111T-315E/TT	MK
MCP111T-450E/TT	ML
MCP111T-475E/TT	MM
MCP112T-195I/TT	MR
MCP112T-240ETT	MS
MCP112T-270E/TT	MA
MCP112T-290E/TT	MB
MCP112T-300E/TT	MC
MCP112T-315E/TT	MD
MCP112T-450E/TT	ME
MCP112T-475E/TT	MF



**Legend:** XX...X Product Code or Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

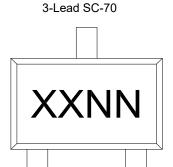
e3 Pb-free JEDEC designator for Matte Tin (Sn)

This package is Pb-free. The Pb-free JEDEC designator (@3)

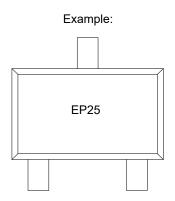
can be found on the outer packaging for this package.

**Note**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or not include the corporate logo.

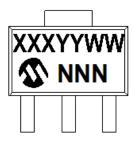
## **Package Marking Information (Continued)**



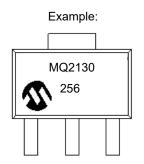
Device	Code
MCP111T-195I/LB	EP
MCP111T-240E/LB	EQ
MCP111T-270E/LB	EG
MCP111T-290E/LB	EH
MCP111T-300E/LB	EJ
MCP111T-315E/LB	EK
MCP111T-450E/LB	EL
MCP111T-475E/LB	EM
MCP112T-195I/LB	ER
MCP112T-240E/LB	ES
MCP112T-270E/LB	EA
MCP112T-290E/LB	EB
MCP112T-300E/LB	EC
MCP112T-315E/LB	ED
MCP112T-450E/LB	EE
MCP112T-475E/LB	EF







Device	Code
MCP111T-195I/MB	MP
MCP111T-240EMB	MQ
MCP111T-270E/MB	MG
MCP111T-290E/MB	NH
MCP111T-300E/MB	MJ
MCP111T-315E/MB	MK
MCP111T-450E/MB	ML
MCP111T-475E/MB	MM
MCP112T-195I/MB	MR
MCP112T-240EMB	MS
MCP112T-270E/MB	MA
MCP112T-290E/MB	MB
MCP112T-300E/MB	MC
MCP112T-315E/MB	MD
MCP112T-450E/MB	ME
MCP112T-475E/MB	MF



**Legend:** XX...X Product Code or Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

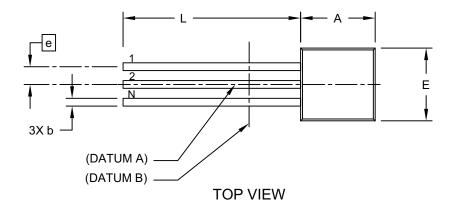
(e3) Pb-free JEDEC designator for Matte Tin (Sn)

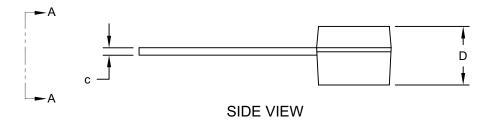
can be found on the outer packaging for this package.

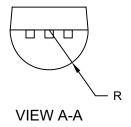
**Note**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or not include the corporate logo.

## 3-Lead Plastic Transistor Outline (TO) [TO-92]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





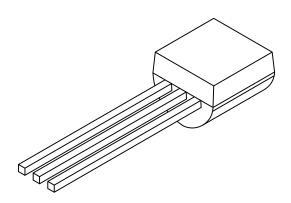


Microchip Technology Drawing C04-101 Rev C Sheet 1 of 2

Note:

## 3-Lead Plastic Transistor Outline (TO) [TO-92]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	INC	HES		
Dimension	Limits	MIN	NOM	MAX
Number of Pins	Ν		3	
Pitch	Pitch e			
Bottom to Package Flat	D	.125	-	.165
Overall Width	Е	.175	-	.205
Overall Length	Α	.170	-	.210
Molded Package Radius	R	.080	-	.105
Tip to Seating Plane	L	.500	-	-
Lead Thickness	С	.014	-	.021
Lead Width	b	.014	_	.022

#### Notes:

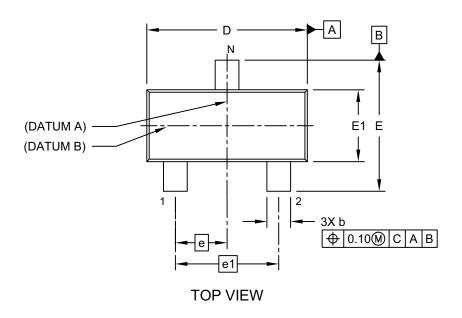
- 1. Dimensions D and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M

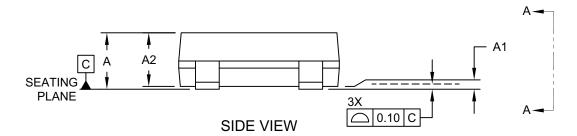
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

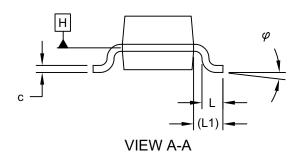
Microchip Technology Drawing C04-101 Rev C Sheet 2 of 2

## 3-Lead Plastic Small Outline Transistor (TT) [SOT-23]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



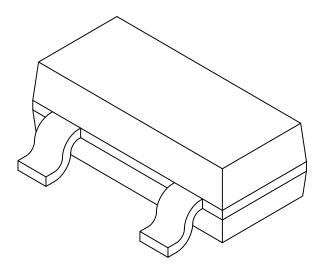




Microchip Technology Drawing C04-104 (TT) Rev C Sheet 1 of 2

## 3-Lead Plastic Small Outline Transistor (TT) [SOT-23]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Number of Pins	N		3	
Lead Pitch	е		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	Α	0.89	1	1.12
Molded Package Thickness	A2	0.79	0.95	1.02
Standoff	A1	0.01	1	0.10
Overall Width	Е	2.10	1	2.64
Molded Package Width	E1	1.16	1.30	1.40
Overall Length	D	2.67	2.90	3.05
Foot Length	L	0.13	0.50	0.60
Footprint	(L1)	0.42 REF		
Foot Angle	$\varphi$	0°	1	10°
Lead Thickness	С	0.08	-	0.20
Lead Width	b	0.30	-	0.54

#### Notes:

- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M

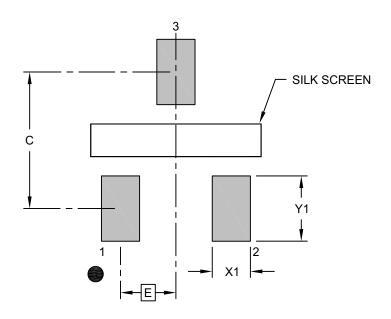
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-104 (TT) Rev C Sheet 2 of 2

## 3-Lead Plastic Small Outline Transistor (TT) [SOT-23]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



## RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е	0.95 BSC		
Contact Pad Spacing	С		2.30	
Contact Pad Width (X3)	X1			0.65
Contact Pad Length (X3)	Y1			1.10

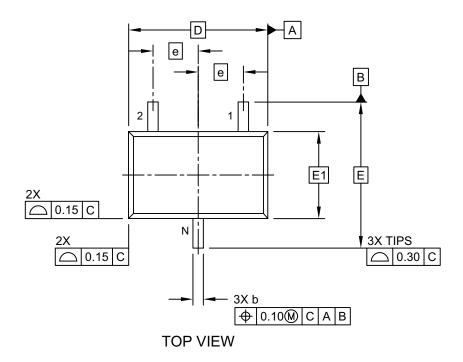
#### Notes:

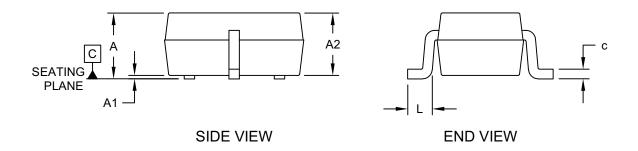
- Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2104 (TT) Rev B

## 3-Lead Plastic Small Outline Transistor (LB) [SC70]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

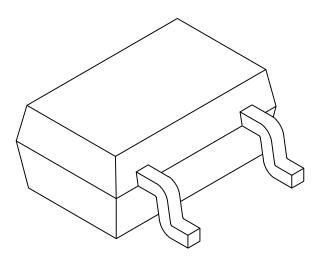




Microchip Technology Drawing C04-060 Rev E Sheet 1 of 2

## 3-Lead Plastic Small Outline Transistor (LB) [SC70]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	N		3		
Pitch	е		0.65 BSC		
Overall Height	Α	0.80	-	1.10	
Standoff	A1	0.00	-	0.10	
Molded Package Thickness	A2	0.80	-	1.00	
Overall Length	D	2.00 BSC			
Overall Width	E	2.10 BSC			
Molded Package Width	E1	1.25 BSC			
Terminal Width	b	0.15	-	0.40	
Terminal Length	L	0.10	0.20	0.46	
Lead Thickness	С	0.08	-	0.26	

#### Notes:

- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M

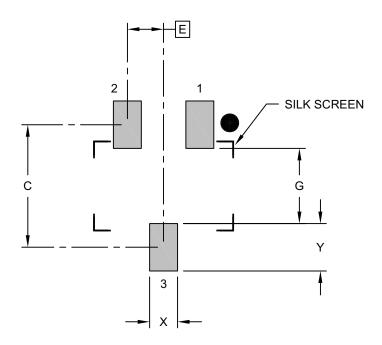
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-060 Rev E Sheet 2 of 2

## 3-Lead Plastic Small Outline Transistor (LB) [SC70]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



#### RECOMMENDED LAND PATTERN

	Units	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX	
Contact Pitch	Е	0.65 BSC			
Contact Pad Spacing	С		2.20		
Contact Pad Width	Х			0.50	
Contact Pad Length	Υ			0.85	
Distance Between Pads	G	1.25			

#### Notes:

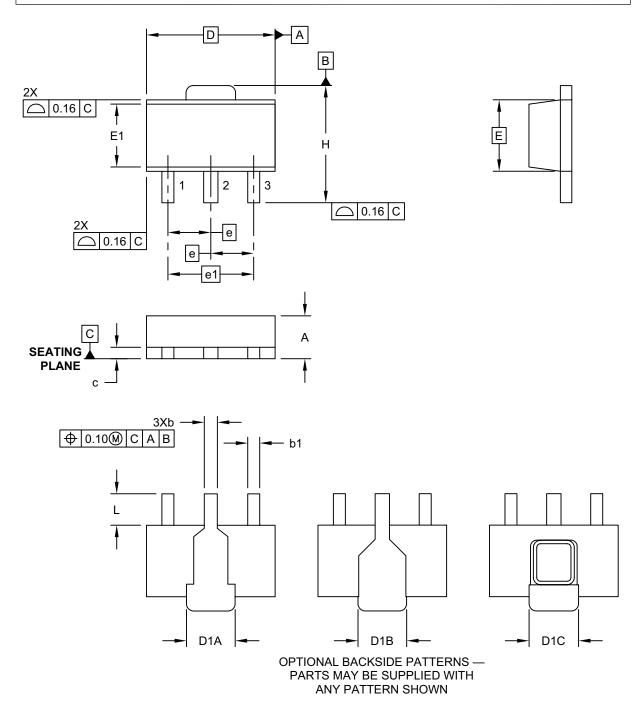
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2060 Rev D

## 3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

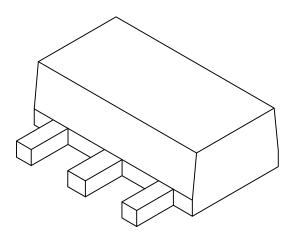
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-029C Sheet 1 of 2

## 3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Number of Leads	N		3	
Pitch	е		1.50 BSC	
Outside Lead Pitch	e1		3.00 BSC	
Overall Height	Α	1.40	1.50	1.60
Overall Width	Н	3.94	4.10	4.25
Molded Package Width at Base	Е	2.50 BSC		
Molded Package Width at Top	E1	2.13	2.20	2.29
Overall Length	D		4.50 BSC	
Tab Length (Option A)	D1A	1.63	1.73	1.83
Tab Length (Option B)	D1B	1.40	1.60	1.75
Tab Length (Option C)	D1C	1.62	1.73	1.83
Foot Length	L	0.79	1.10	1.20
Lead Thickness	С	0.35	0.40	0.44
Lead 2 Width	b	0.41	0.50	0.56
Leads 1 & 3 Width	b1	0.36	0.42	0.48

#### Notes:

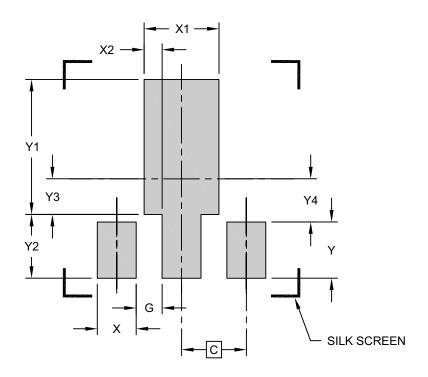
- 1. Dimensions D and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-029C Sheet 2 of 2

## 3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



## RECOMMENDED LAND PATTERN

Units	MILLIMETERS					
Dimension Limits	MIN	NOM	MAX			
С		1.50 (BSC)				
X (3 PLACES)		0.900				
X1		1.733				
X2 (2 PLACES)		0.416				
G (2 PLACES)		0.600				
Y (2 PLACES)		1.300				
Y1		3.125				
Y2		1.475				
Y3		0.825				
Y4		1.000				

#### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

 ${\it BSC: Basic Dimension. Theoretically exact value shown without tolerances.}$ 

Microchip Technology Drawing C04-2029C

## 5.2 Product Tape and Reel Specifications

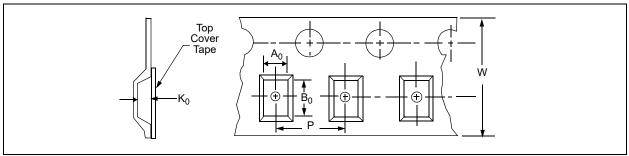


FIGURE 5-1: Embossed Carrier Dimensions (8, 12, 16 and 24 mm tape only).

## **CARRIER TAPE/CAVITY DIMENSIONS**

Case	3					าร	Output Quantity	Reel Diameter in	
Outline			W mm	P mm	A0 mm	B0 mm	K0 mm	Units	mm
TT	SOT-23	3L	8	4	3.15	2.77	1.22	3000	180
LB	SC-70	3L	8	4	2.4	2.4	1.19	3000	180

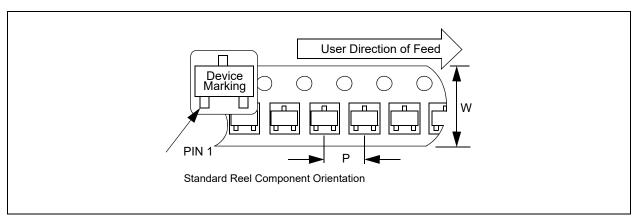


FIGURE 5-2: 3-Lead SOT-23/SC70 Device Tape and Reel Specifications.

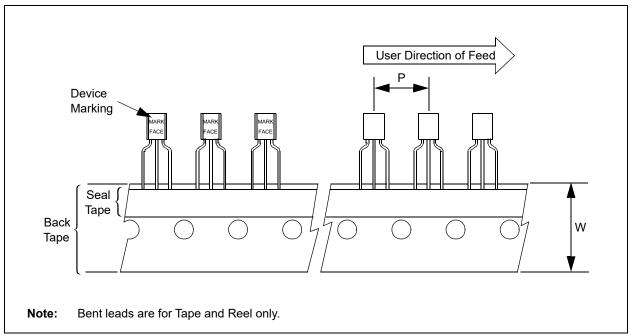


FIGURE 5-3: TO-92 Devices.

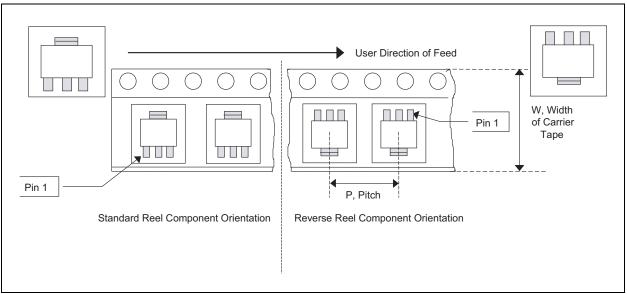


FIGURE 5-4: SOT-89 Devices.

N/	Ρ1	4	4	14	14	7
IVI	ГІ					

NOTES:

## APPENDIX A: REVISION HISTORY

#### **Revision G (November 2022)**

- · Updated document layout.
- Added automotive qualification to Features and examples to Product Identification System.
- Updated Absolute Maximum Ratings and Section 5.0 "Packaging information".

## Revision F (July 2016)

- Updated Table 3-1.
- Updated Section 5.0 "Packaging information".
- · Minor typographical corrections.

## **Revision E (January 2013)**

· Added a note to each package outline drawing.

## Revision D (June 2005)

· Added SOT-89-3 package information throughout.

#### Revision C (March 2005)

- Added Section 4.4 "Using in PIC® Microcontroller ICSP™ Applications (MCP111 only)" on using the MCP111 in PIC microcontroller ICSP applications.
- Added V<sub>ODH</sub> specifications in Section 1.0 "Electrical Characteristics" (for ICSP applications).
- · Added Figure 2-28.
- · Added devices features table to page 1.
- Updated SC-70 package markings and added Pbfree marking information to Section 5.0 "Packaging information".
- · Added Appendix A: "Revision History".

## **Revision B (August 2004)**

 Corrected package marking information in Section 5.0 "Packaging information".

#### Revision A (May 2004)

· Original release of this document.

N/	Ρ1	1	1	11	1	7
IVI				/ I		

NOTES:

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X1	XXX >	<u>xx</u>	xxx	Exa	mples:	
Device Tape/Ree Option	Monitoring Tempe Options Rar	rature Package	Qualification	a)	MCP111T-195I/TT:	1.90V option, open-drain, -40°C to +85°C,
Device:	MCP111: MicroPower V MCP112: MicroPower V			b)	MCP111T-315E/LB:	SOT-23B package. Tape and Reel, 3.08V option, open-drain, -40°C to +125°C, SC-70-3 package.
Tape and Reel Option:	(blank) = BAG (1000/B T = Tape and Rec			c)	MCP111-300E/TO:	2.93V option, open-drain, -40°C to +125°C, 3-Lead TO-92 package.
Monitoring Options:	195 = 1.90V 240 = 2.32V			d)	MCP111-315E/MB:	3.08V option, open-drain, -40°C to +125°C, SOT-89-3 package.
	270 = 2.63V 290 = 2.90V 300 = 2.93V 315 = 3.08V 450 = 4.38V			e)	MCP111T-270E/LBV	VAO: Tape and Reel, 2.63V option, open-drain, -40°C to +125°C, 3-lead SC-70 package, Automotive Qualified.
Temperature Range:		°C (MCP11X-195 or 5°C (Except MCP11		f)	MCP111T-290E/TT	VAO: Tape and Reel, 2.90V, open-drain, -40°C to +125°C, 3-lead SOT-23B package, Automotive Qualified.
Package:	LB = SC-70, 3-lead MB = SOT-89, 3-lead TO = TO-92, 3-lead	ad	,	g)	MCP111T-450E/TTV	VAO: Tape and Reel, 4.38V, open-drain, –40°C to +125°C, 3-lead SOT-23B package,
Qualification*:	TT = SOT-23B, 3-le	ead		h)	MCP111T-315E/MB	Automotive Qualified. VAO: Tape and Reel 3.08V option, open-drain, –40°C to +125°C,
Quanneation":		EC-Q100 Qualified variants are:	VAO			3-lead SOT-89 package, Automotive Qualified.
	MCP111T-300E/LBVAO, MCP111T-290E/LBVAO, MCP111T-290E/TTVAO, MCP111T-315E/TTVAO,	MCP111T-315E/LB\ MCP111T-270E/TT\ MCP111T-300E/TT\ MCP111T-450E/TT\	/AO, /AO, /AO, /AO.	a)	MCP112T-290E/TT:	Tape and Reel, 2.90V option, push-pull, -40°C to +125°C, SOT-23B-3 package.
	Contact your local Microc automotive qualified varia voltage options.			b)	MCP112T-475E/LB	
				c)	MCP112-450E/TO:	4.38V option, push-pull, –40°C to +125°C, TO-92-3 package.
				d)	MCP112-315E/MB:	3.08V option, push-pull, -40°C to +125°C, SOT-89-3 package.
				Note	catalog part n fier is used for printed on the your Microchi	I identifier only appears in the umber description. This identi- ordering purposes and is not device package. Check with p Sales Office for package h the Tape and Reel option.

M	IC	<b>P1</b>	1	1	/1	1	2
	$\mathbf{U}$				, ,		_

NOTES:

#### Note the following details of the code protection feature on Microchip products:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner, within operating specifications, and under normal conditions.
- Microchip values and aggressively protects its intellectual property rights. Attempts to breach the code protection features of Microchip product is strictly prohibited and may violate the Digital Millennium Copyright Act.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not
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